

600mA LDO Linear Regulator

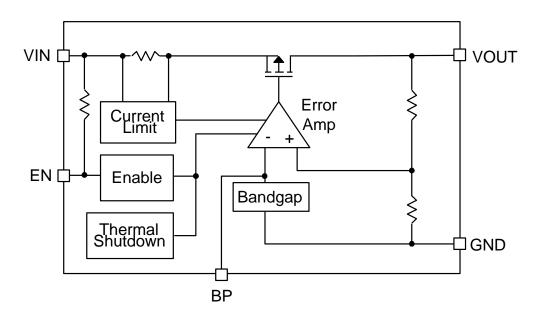
❖ GENERAL DESCRIPTION

The AX6606 is a low dropout, positive linear regulator with very low quiescent. It can supply up to 600mA output current. The BP pin with a 10nF bypass capacitor can help reduce the output noise level. The characteristics of low dropout voltage and less guiescent current make it good for some critical current application, for example, some battery powered devices. The typical guiescent current is approximately 50µA. In the shutdown mode, the maximum supply current is less than 1uA. The AX6606 regulator is able to operate with output capacitors as small as 2.2uF for stability. The AX6606 series are offering several fixed output voltage types including 1.0V, 1.1V, 1.2V, 1.3V and 1.4V. Built-in current-limit and thermal-shutdown functions prevent any fault condition from IC damage.

*** FEATURES**

- Input voltage range: 2.6V~5.5V
- 1.0V/1.1V/1.2V/1.3V/1.4V fixed output voltages
- Guaranteed 600mA output current
- Very Low quiescent current at 50µA (typ.)
- Maximum supply current in shutdown mode <1uA
- Current limit and thermal shutdown protection
- Short circuit current fold-back
- Available in the SOT-23-5L and TDFN-6L Pb-Free Packages

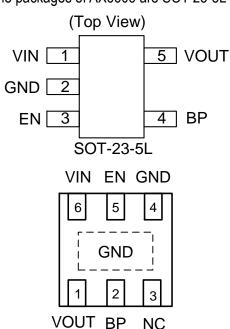
❖ BLOCK DIAGRAM





❖ PIN ASSIGNMENT

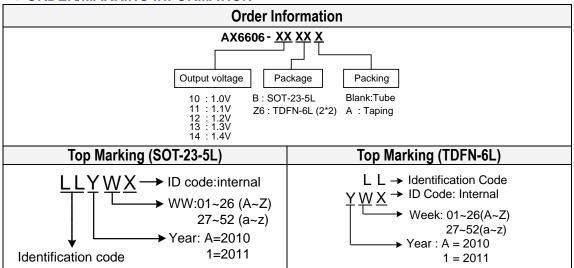
The packages of AX6606 are SOT-23-5L and TDFN-6L; the pin assignment is given by:



Name	Description						
	Voltage input. The input capacitor in						
VIN	the range of 2.2uF to 10uF is						
	sufficient.						
GND	Ground						
EN	Enable pin (Active High)						
	Output Voltage, The AX6606 is						
VOUT	stable with an output capacitor						
	2.2uF for greater.						
DD	Reference Noise Bypass						
BP	(The Bypass capacitor ≧1nF						
NC	No Connect Pin						

❖ ORDER/MARKING INFORMATION

TDFN-6L (2*2) (TOP VIEW)



Appendix

Part Number	Identification Code
AX6606-1.0V	Fb
AX6606-1.1V	Fc
AX6606-1.2V	Fd
AX6606-1.3V	Fe
AX6606-1.4V	Ff



❖ ABSOLUTE MAXIMUM RATINGS (at T_A=25 °C)

Characteristics	Symbol	Rating	Unit		
V _{IN} Pin Voltage			GND - 0.3 to GND + 6	V	
Output Voltage	V _{OUT}	GND - 0.3 to V _{IN} + 0.3	V		
Enable Voltage		V _{EN}	GND - 0.3 to GND + 6	V	
BP Pin Voltage	V_{BP}	GND - 0.3 to GND + 6	٧		
Dower Dissination	SOT-23-5L	PD	400	mW	
Power Dissipation	TDFN-6L	ן אי	830		
Storage Temperature Range	T _{ST}	-40 to +150	°C		
Operating Temperature Range	T _{OP}	-40 to +85	°C		
Junction Temperature	TJ	-40 to +125	°C		
Thermal Resistance from Junction to case	SOT-23-5L	Δ	180	°C/W	
Thermal Resistance from Junction to case	TDFN-6L	$\theta_{ m JC}$	25	C/VV	
Thermal Resistance from Junction to ambient	SOT-23-5L	Δ	250	°C/W	
Thermal Resistance from Junction to ambient	TDFN-6L	θ_{JA}	120	C/VV	

Note: θ_{JA} is measured with the PCB copper area of approximately 1 in²(Multi-layer).

❖ ELECTRICAL CHARACTERISTICS (V_{IN}=5V, T_A=25 °C, unless otherwise noted)

Characteristics	Symbol	Conditions		Min	Тур	Max	Units
Input Voltage	V _{IN}	I _{OUT} =30mA (Note1)		2.6	-	5.5	V
Quiescent Current	IQ	I _{OUT} =0mA		-	50	-	μΑ
Shutdown Current	I _{SD}	V _{EN} =0V		-	-	1	μΑ
Output Voltage Accuracy	ΔV_{OUT}	V _{IN} =2.6V to 5.5V, I _{OUT} =1mA		-3	ı	+3	%
Dropout Voltage (Note2)	V_{DROP}	I _{OUT} =600mA		-	ı	1700	mV
Current Limit	I _{LIMIT}			700	-	-	mΑ
Short Circuit Current	I _{Short}	Output Voltage < 0.375*V _{OUT}		-	300	ı	mA
Load Regulation (Note 3)	ΔV_{LOAD}	$I_{OUT} = 10 \text{m} \sim 0.6 \text{A}$		-	10	30	mV
	PSRR	C _{IN} =2.2uF,	F=120Hz	-	65	ı	
Ripple Rejection		C_{OUT} =2.2uF, I_{OUT} =10mA	F=1KHz	-	55	ı	dB
Enable Input Threshold	V_{ENH}			1.5	-	-	V
Enable Input Threshold	V_{ENL}			-	-	0.4	V
Enable Pin Current	I _{ENH}	V _{EN} =V _{IN}		-	0.003	0.1	
Enable Fill Currefit	I _{ENL}	V _{EN} =0V		-	0.35	1	μA
Temperature Shutdown	Ts			-	140	-	°C
Temperature Shutdown Hysterisis T _{SH}				-	30	-	°C

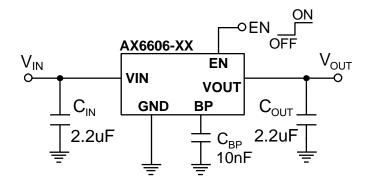
Note1. Minimum V_{IN} voltage is defined by output adds a dropout voltage.

Note2. The dropout voltage is defined as V_{IN}-V_{OUT}, which is measured when V_{OUT} drop about 100mV.

Note3. Regulation is measured at constant junction temperature by using pulsed testing with a low ON time.



❖ APPLICATION CIRCUIT



FUNCTION DESCRIPTIONS

A minimum of 2.2uF capacitor must be connected from Vout to ground to insure stability. Typically a large storage capacitor is connected from V_{IN} to ground to ensure that the input voltage does not sag below the minimum dropout voltage during the load transient response. This pin must always be dropout voltage higher than V_{OUT} in order for the device to regulate properly.

APPLICATION INFORMATION

Like any low-dropout regulator, the AX6606 requires input and output decoupling capacitors. The device is specifically designed for portable applications requiring minimum board space and smallest components. These capacitors must be correctly selected for good performance. Please note that linear regulators with a low dropout voltage have high internal loop gains which require care in quarding against oscillation caused by insufficient decoupling capacitance.

Capacitor Selection

Normally, use a 2.2uF capacitor on the input and a 2.2uF capacitor on the output of the AX6606. Larger input capacitor values and lower ESR (X5R, X7R) provide better supply-noise rejection and transient response. A higher-value output capacitor (4.7uF) may be necessary if large, fast transients are anticipated and the device is located several inches from the power source.

Input-Output (Dropout) Voltage

A regulator's minimum input-to-output voltage differential (dropout voltage) determines the lowest usable supply voltage. In battery-powered systems, this determines the useful end-of-life battery voltage. Because the device uses a PMOS, its dropout voltage is a function of drain-to source on-resistance, R_{DS (ON)}, multiplied by the load current:



Current Limit and Thermal Shutdown Protection

In order to prevent overloading or thermal condition from damaging the device, AX6606 regulator has internal thermal and current limiting functions designed to protect the device. It will rapidly shut off PMOS pass element during overloading or over temperature condition.

Thermal Considerations

The AX6606 series can deliver a current of up to 600mA over the full operating junction temperature range. However, the maximum output current must be dated at higher ambient temperature to ensure the junction temperature does not exceed 125°C. With all possible conditions, the junction temperature must be within the range specified under operating conditions. Power dissipation can be calculated based on the output current and the voltage drop across regulator.

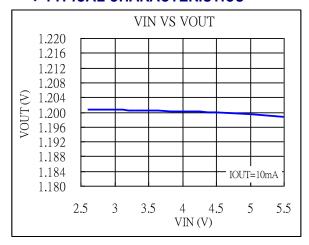
The final operating junction temperature for any set of conditions can be estimated by the following thermal equation:

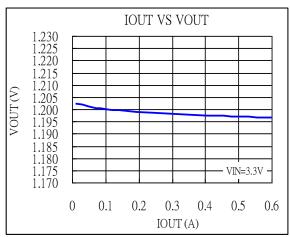
PD (MAX) =
$$(T_{J (MAX)} - T_A) / \theta_{JA}$$

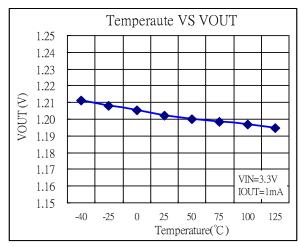
Where T_{J (MAX)} is the maximum junction temperature of the die (125°C) and T_A is the maximum ambient temperature. The junction to ambient thermal resistance (θ_{JA}) for SOT-23-5L package at recommended minimum footprint is 250°C/W.

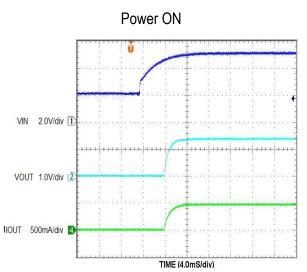


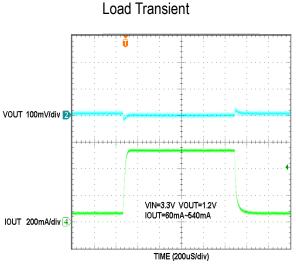
❖ TYPICAL CHARACTERISTICS







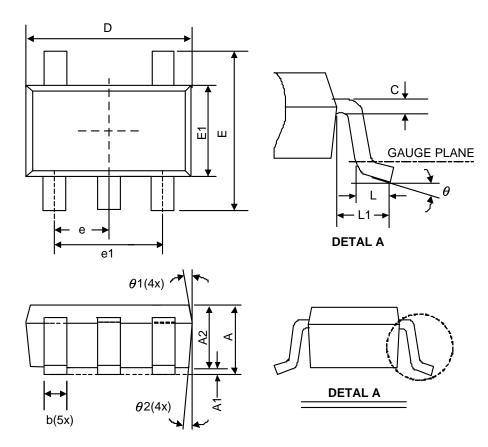






❖ PACKAGE OUTLINES

(1) SOT-23-5L

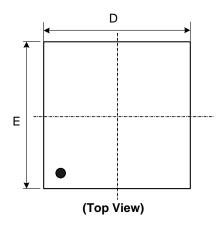


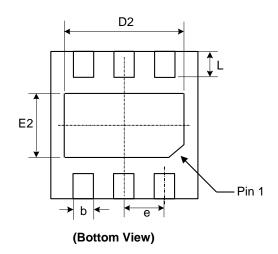
Cumbal	Dimensions in Millimeters			Dimensions in Inches			
Symbol	Min.	Nom.	Max.	Min.	Nom.	Max.	
Α	-	-	1.45	-	-	0.057	
A1	0	0.08	0.15	0	0.003	0.006	
A2	0.9	1.1	1.3	0.035	0.043	0.051	
b	0.3	0.4	0.5	0.012	0.016	0.02	
С	0.08	0.15	0.22	0.003	0.006	0.009	
D	2.7	2.9	3.1	0.106	0.114	0.122	
E1	1.4	1.6	1.8	0.055	0.063	0.071	
E	2.6	2.8	3	0.102	0.11	0.118	
L	0.3	0.45	0.6	0.012	0.018	0.024	
L1	0.5	0.6	0.7	0.02	0.024	0.028	
e1		1.9 BSC 0.075 BSC					
е		0.95 BSC			0.037 BSC		
θ	00	40	8°	0°	40	8°	
θ 1	5°	10∘	15°	5°	10°	15°	
θ 2	5∘	10∘	15°	5∘	10°	15°	

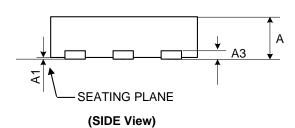
JEDEC outline: MO-178 AA



(2) TDFN-6L (2*2 0.75mm)







Cumbal	Dimensions in Millimeters			Dimensions in Inches			
Symbol	Min.	Nom.	Max.	Min.	Nom.	Max.	
Α	0.70	0.75	0.80	0.028	0.030	0.031	
A1	0.00	0.02	0.05	0.000	0.001	0.002	
A3		0.203 REF.		0.008 REF.			
b	0.20	0.28	0.35	0.009	0.011	0.013	
D	1.95	2.00	2.05	0.077	0.079	0.081	
D2	1.35	1.50	1.65	0.055	0.059	0.063	
Е	1.95	2.00	2.05	0.077	0.079	0.081	
E2	0.75	0.90	1.05	0.031	0.035	0.039	
е	0.65 BSC.			0.65 BSC. 0.026 BSC.			
L	0.20	0.30	0.40	0.008	0.012	0.016	